Supporting Information

Perovskite Photodetectors Prepared by Flash Evaporation Printing

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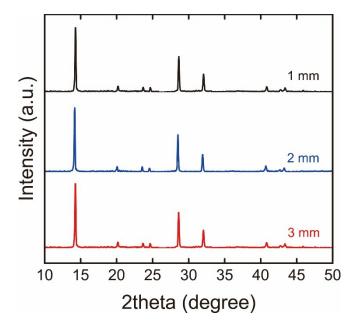


Fig. S1 XRD patterns of the perovskite thin films evaporated through different distances between the source and the substrate.

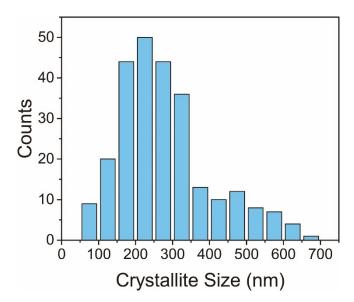


Fig. S2 Crystallite size distribution of the perovskite thin film in Fig. 2a.

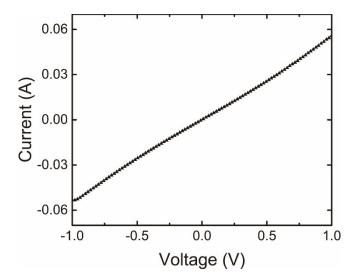


Fig. S3 *I-V* characteristics of the FTO/MAPbI₃/Au device for determination of the electrical conductivity.